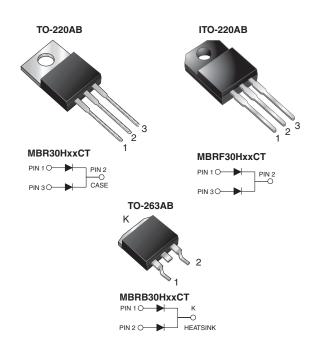
MBR(F,B)30H35CT thru MBR(F,B)30H60CT

Vishay General Semiconductor

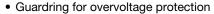
Dual Common-Cathode Schottky Rectifier

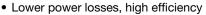
High Barrier Technology for Improved High Temperature Performance



PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 15 A					
V _{RRM}	35 V to 60 V					
I _{FSM}	150 A					
V _F	0.56 V, 0.59 V					
I _R	80 μΑ, 60 μΑ					
T _J max.	175 °C					

FEATURES





- Low forward voltage drop
- · Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters or polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix

meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)								
PARAMETER		SYMBOL	MBR30H35CT	MBR30H45CT	MBR30H50CT	MBR30H60CT	UNIT	
Maximum repetitive peak reverse voltage		V_{RRM}	35	45	50	60	V	
Working peak reverse voltage		V_{RWM}	35	45	50	60	V	
Maximum DC blocking voltage		V_{DC}	35	45	50	60	V	
waxiinumaverage forward rectified	total device	,	30					
	per diode	I _{F(AV)}	15					
Peak forward surge current 8.3 ms s sine-wave superimposed on rated lo		I _{FSM}	150			Α		
Peak repetitive reverse surge current at $t_p = 2 \mu s$, 1 kHz	per diode	I _{RRM}	1.0 0.5			Α		
Peak non-repetitive reverse energy (8/20 µs waveform)		E _{RSM}	25 20		mJ			



MBR(F,B)30H35CT thru MBR(F,B)30H60CT

www.vishay.com

Vishay General Semiconductor

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	. MBR30H35CT MBR30H45CT MBR30H50CT MBR30H60CT						
Non-repetitive avalanche energy per diode at 25 °C, I _{AS} = 4 A, L = 10 mH	E _{AS}	80						
Electrostatic discharge capacitor voltage human body model: C = 100 pF, R = 1.5 k Ω	V _C	25				kV		
Voltage rate of change (rated V _R)	dV/dt	10 000				V/µs		
Operating junction and storage temperature range	T _J , T _{STG}	- 65 to + 175				°C		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500				V		

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	MBR30H35CT MBR30H45CT		MBR30H50CT MBR30H60CT		UNIT
Maximum instantaneous forward voltage per diode ⁽¹⁾	I _F = 15 A	T _C = 25 °C	V _F	-	0.62	-	0.68	V
	I _F = 15 A	T _C = 125 °C		0.49	0.56	0.55	0.59	
	$I_F = 30 \text{ A}$	T _C = 25 °C		-	0.73	-	0.83	
	$I_F = 30 \text{ A}$	T _C = 125 °C		0.62	0.67	0.68	0.71	
Maximum reverse current per diode at		T _J = 25 °C	I _R	ı	80	-	60	μA
working peak reverse voltage (2)		T _J = 125 °C		5.0	15	4.0	15	mA

Notes

 $^{(1)}$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL MBR MBRF MBRB UNIT						
Typical thermal resistance junction to case per diode	$R_{ heta JC}$	1.5	4.5	1.5	°C/W		

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	MBR30H45CT-E3/45	1.85	45	50/tube	Tube			
ITO-220AB	MBRF30H45CT-E3/45	1.99	45	50/tube	Tube			
TO-263AB	MBRB30H45CT-E3/45	1.35	45	50/tube	Tube			
TO-263AB	MBRB30H45CT-E3/81	1.35	81	800/teel	Tape and reel			
TO-220AB	MBR30H45CTHE3/45 (1)	1.85	45	50/tube	Tube			
ITO-220AB	MBRF30H45CTHE3/45 (1)	1.99	45	50/tube	Tube			
TO-263AB	MBRB30H45CTHE3/45 (1)	1.35	45	50/tube	Tube			
TO-263AB	MBRB30H45CTHE3/81 (1)	1.35	81	800/teel	Tape and reel			

Note

(1) AEC-Q101 qualified



Vishay General Semiconductor

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

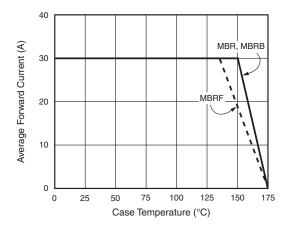


Fig. 1 - Forward Derating Curve

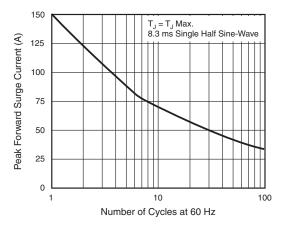


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

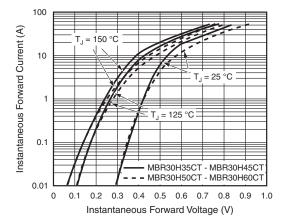


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

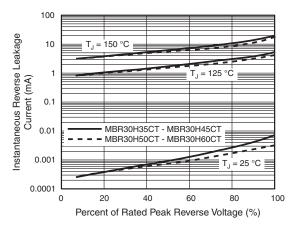


Fig. 4 - Typical Reverse Characteristics Per Diode

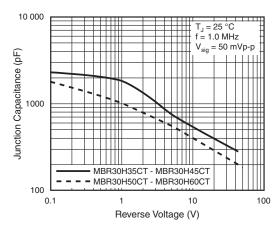


Fig. 5 - Typical Junction Capacitance Per Diode

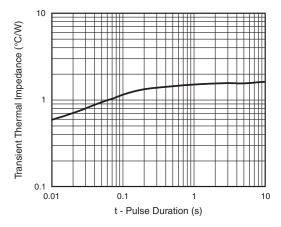


Fig. 6 - Typical Transient Thermal Impedance Per Diode



MBR(F,B)30H35CT thru MBR(F,B)30H60CT

Vishay General Semiconductor

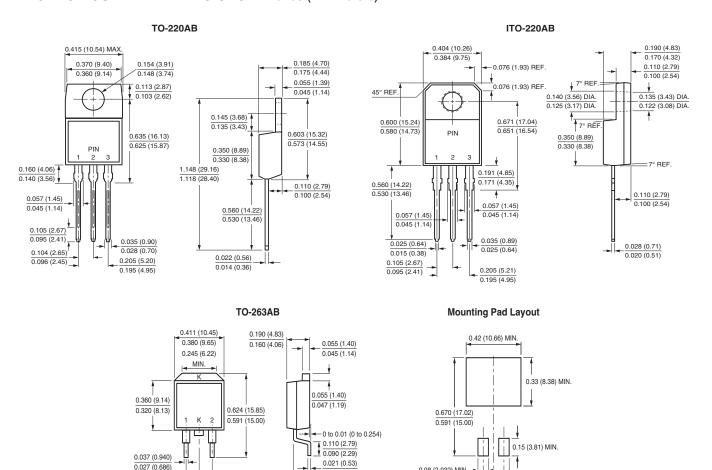
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

0.105 (2.67)

0.095 (2.41)

0.205 (5.20)

0.195 (4.95)



0.140 (3.56)

0.110 (2.79)

0.08 (2.032) MIN.

0.105 (2.67)

0.095 (2.41)



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Revision: 02-Oct-12 Document Number: 91000